Vishay Semiconductors

www.vishay.com

Ultrafast Rectifier, 2 x 5 A FRED Pt[®]



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|-----------------|--|--|--|
| Package | SMPD (TO-263AC) | | | |
| I _{F(AV)} | 2 x 5 A | | | |
| V _R | 600 V | | | |
| V _F at I _F | 1 V | | | |
| t _{rr} | 35 ns | | | |
| T _J max. | 175 °C | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

Ultrafast recovery time, reduced Q_{rr}, and soft recovery



COMPLIANT HALOGEN

FREE

- 175 °C maximum operating junction temperature
- For PFC CRM / CCM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

| ABSOLUTE MAXIMUM RA | TINGS | | | | |
|-----------------------------------|------------|------------------|--|--------|-------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Peak repetitive reverse voltage | | V _{RRM} | | 600 | V |
| Average rectified forward current | per device | | T _ 152 °C | 10 | |
| Average rectilied forward current | per diode | IF(AV) | T _{solder pad} = 153 °C | 5 | |
| Non repetitive peak aurge aurgent | per device | 1 | | 110 | A |
| Non-repetitive peak surge current | per diode | IFSM | $T_J = 25 \text{ °C}, 6 \text{ ms} \text{ square pulse}$ | 60 | Ī |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|-----------------|---|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Breakdown voltage, blocking voltage | V_{BR}, V_{R} | I _R = 100 μA | 600 | - | - | | |
| Forward voltage, per diode | V _F | I _F = 5 A | - | 1.2 | 1.5 | V | |
| | | I _F = 5 A, T _J = 150 °C | - | 1 | 1.25 | | |
| Deverse leakage averant ner diade | I _R | $V_{R} = V_{R}$ rated | - | - | 3 | | |
| Reverse leakage current, per diode | | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | - | 15 | 150 | μA | |
| Junction capacitance, per diode | CT | V _R = 600 V | - | 6 | - | pF | |

Revision: 06-Apr-2022

1

Document Number: 96518

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



www.vishay.com

Vishay Semiconductors

| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | |
|---|------------------|---|--|------|------|-------|----|
| PARAMETER | SYMBOL | TEST CO | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$ | õs, V _R = 30 V | - | 35 | - | |
| Bayaraa raaayar (tima | + | I _F = 0.5 A, I _R = 1 A, I _{rr} | = 0.25 A | - | - | 35 | ns |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 45 | - | |
| | | T _J = 125 °C | | - | 70 | - | |
| Deals reasoning as meant | I _{RRM} | T _J = 25 °C | I _F = 5 A, dI _F /dt = 500 A/μs, V _B = 400 V | - | 7 | - | Α |
| Peak recovery current | | T _J = 125 °C | | - | 10 | - | A |
| | 0 | T _J = 25 °C | | - | 160 | - | nC |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 370 | - | nC |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-----------------------------------|----------------------------|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | +175 | °C |
| Thermal resistance, per diode junction to mount | R _{thJM} | | - | 2.4 | 3.3 | °C/W |
| Approximate weight | | | | 0.55 | | g |
| Marking device | | Case style SMPD (TO-263AC) | | 10CI | DU06 | |



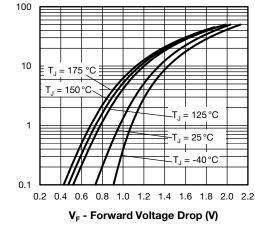


Fig. 1 - Typical Forward Voltage Drop Characteristics

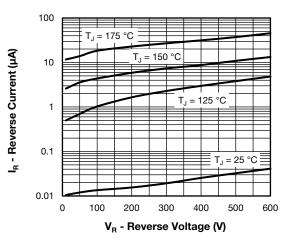


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



Vishay Semiconductors

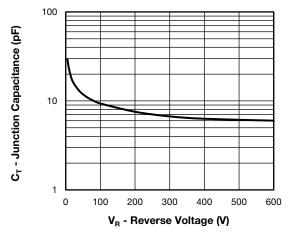


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

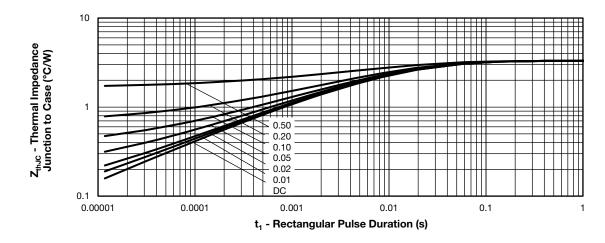
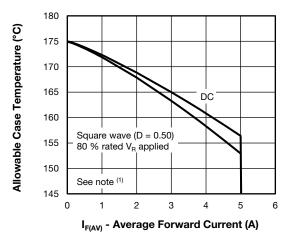
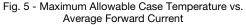


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)



www.vishay.com



Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 5); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

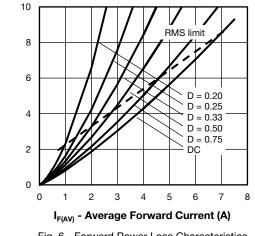


Fig. 6 - Forward Power Loss Characteristics

Revision: 06-Apr-2022

3

Document Number: 96518

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

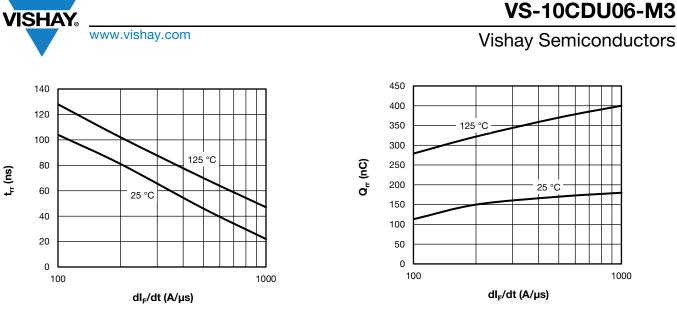


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt

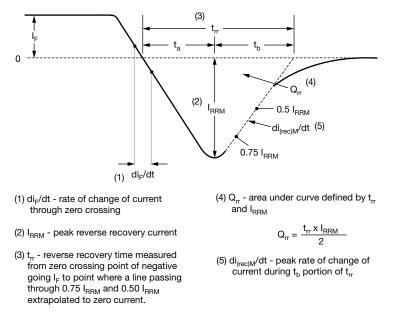


Fig. 9 - Reverse Recovery Waveform and Definitions

Vishay Semiconductors

www.vishay.com

ORDERING INFORMATION TABLE

| Device code | VS- | 10 | С | D | U | 06 | -M3 |
|-------------|-----|--------|-----------|-----------|----------|---------|-----------|
| | ••• | 10 | • | | 0 | 00 | |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
| | 1 | - Visl | nay Sem | nicondu | ctors pr | oduct | |
| | 2 · | - Cur | rent rati | ng (10 A | A) | | |
| | 3 · | - Circ | cuit conf | figuratio | n: | | |
| | | C = | commo | on catho | de | | |
| | 4 | - D = | SMPD | package | Э | | |
| | 5 | - Pro | cess typ | be, | | | |
| | | U = | ultrafas | t recove | ery | | |
| | 6 | - Volt | tage coo | de (06 = | 600 V) | | |
| | 7 | M3 | 3 = halog | gen-free | e, RoHS | -compli | iant, and |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|---|------|-----------------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPT | | | | | |
| VS-10CDU06-M3/I | 2000 | 2000 | 13"diameter plastic tape and reel | | | |

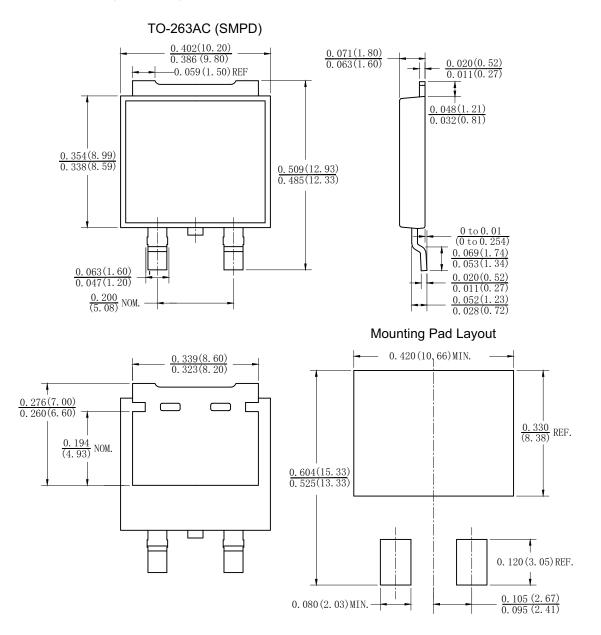
| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?95604 | | | | |
| Part marking information | www.vishay.com/doc?95566 | | | | |
| Packaging information | www.vishay.com/doc?88869 | | | | |





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1